

TO-92S



Pin Definition:

1. V_{CC}
2. GND
3. Output

TSOT-23



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2. Output
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Description

TSH251 Hall-effect sensor is a temperature stable, stress-resistant, Low Tolerance of Sensitivity micro-power switch. Superior high-temperature performance is made possible through a dynamic offset cancellation that utilizes chopper-stabilization. This method reduces the offset voltage normally caused by device over molding, temperature dependencies, and thermal stress. TSH251 is special made for low operation voltage, 1.65V, to active the chip which includes the following on a single silicon chip: voltage regulator, Hall voltage generator, small-signal amplifier, chopper stabilization, Schmitt trigger, CMOS output driver. Advanced CMOS wafer fabrication processing is used to take advantage of low-voltage requirements, component matching, very low input-offset errors, This device requires the presence of omni-polar magnetic fields for operation.

Features

- CMOS Hall IC Technology
- Strong RF noise protection
- 1.65 to 3.5V for battery-powered applications
- Omni polar, output switches with absolute value of North or South pole from magnet
- Operation down to 1.65V, Micropower consumption
- High Sensitivity for reed switch replacement applications
- Low sensitivity drift in crossing of Temp. range
- Ultra Low power consumption at 5uA (Avg)
- High ESD Protection, HBM > ±4KV(min)
- Totem-pole output

Ordering Information

Part No.	Package	Packing
TSH251CT B0G	TO-92S	1Kpcs / Bulk Bag
TSH251CX RFG	TSOT-23	3Kpcs / 7" Reel

Note: "G" denote for Halogen Free Product

Application

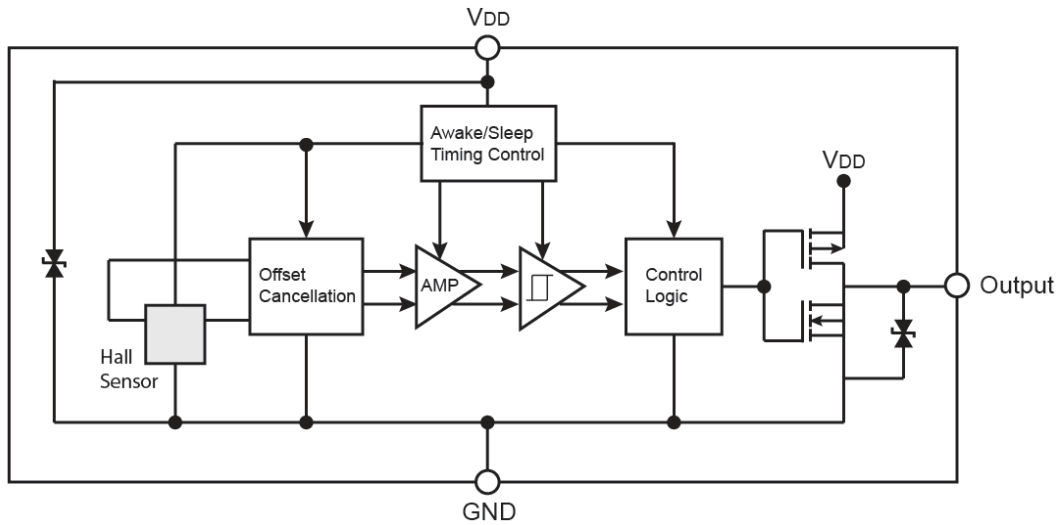
- Solid state switch
- Handheld Wireless Handset Awake Switch (Flip Cell/PHS Phone/Note Book/Flip Video Set)
- Lid close sensor for battery powered devices
- Magnet proximity sensor for reed switch replacement in low duty cycle applications
- Water Meter, Floating Meter

Absolute Maximum Rating (Ta = 25°C unless otherwise noted)

Characteristics	Limit	Value	Unit
Supply voltage	V _{DD}	4.5	V
Output Voltage	V _{OUT}	4.5	V
Reverse Voltage	V _{DD/OUT}	-0.3	V
Magnetic flux density		Unlimited	Gauss
Output current	I _{OUT}	1	mA
Operating temperature range	T _{OPR}	-40 to +85	°C
Storage temperature range	T _{STG}	-65 to +150	°C
Maximum Junction Temp	T _J	150	°C
Thermal Resistance - Junction to Ambient	TO-92S	206	°C/W
	TSOT-23	543	
Thermal Resistance - Junction to Case	TO-92S	148	°C/W
	TSOT-23	410	
Package Power Dissipation	TO-92S	606	mW
	TSOT-23	230	

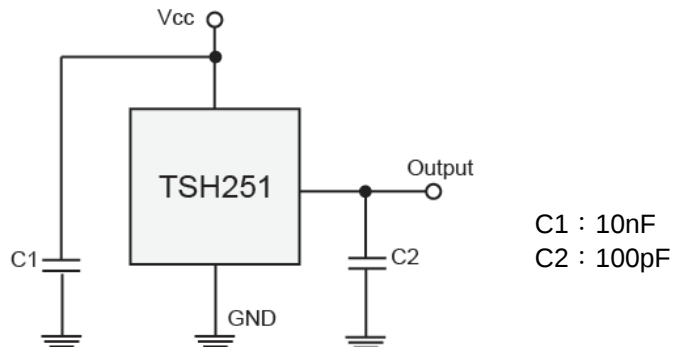
Note: Exceeding the absolute maximum ratings may cause permanent damage. Exposure to absolute maximum-rated conditions for extended periods may affect device reliability.

Block Diagram



Note: Static sensitive device; please observe ESD precautions. Reverse VDD protection is not included. For reverse voltage protection, a 100Ω resistor in series with VDD is recommended.

Typical Application Circuit



Electrical Specifications (DC Operating Parameters : $T_A=+25^{\circ}\text{C}$, $V_{DD}=1.8\text{V}$)

Parameters	Test Conditions	Min	Typ	Max	Units
Supply Voltage	Operating	1.65	--	3.5	V
Supply Current	Awake State	--	1.4	3	mA
	Sleep State	--	3.6	7	μA
	Average	--	5	10	μA
Output Leakage Current	Output off	--	--	1	uA
Output High Voltage	IOUT=0.5mA(Source)	VDD-0.2	--	--	V
Output Low Voltage	IOUT=0.5mA(Sink)	--	--	0.2	V
Awake mode time	Operating	--	40	80	uS
Sleep mode time	Operating	--	40	80	mS
Duty Cycle		--	0.1	--	%
Electro-Static Discharge	HBM	4			KV

Magnetic Specifications (TSH251CT)

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Operating Point	B _{OPS}	S pole to branded side, B > B _{OP} , Vout On		30	55	Gauss
	B _{OPN}	N pole to branded side, B > B _{OP} , Vout On	-55	-30		Gauss
Release Point	B _{RPS}	S pole to branded side, B < B _{RP} , Vout Off	10	20		Gauss
	B _{RPN}	N pole to branded side, B < B _{RP} , Vout Off		-20	-10	Gauss
Hysteresis	B _{HYS}	B _{OPX} - B _{RPX}		10		Gauss

Note: 1G (Gauss) = 0.1mT (millitesta)

Magnetic Specifications (TSH251CX)

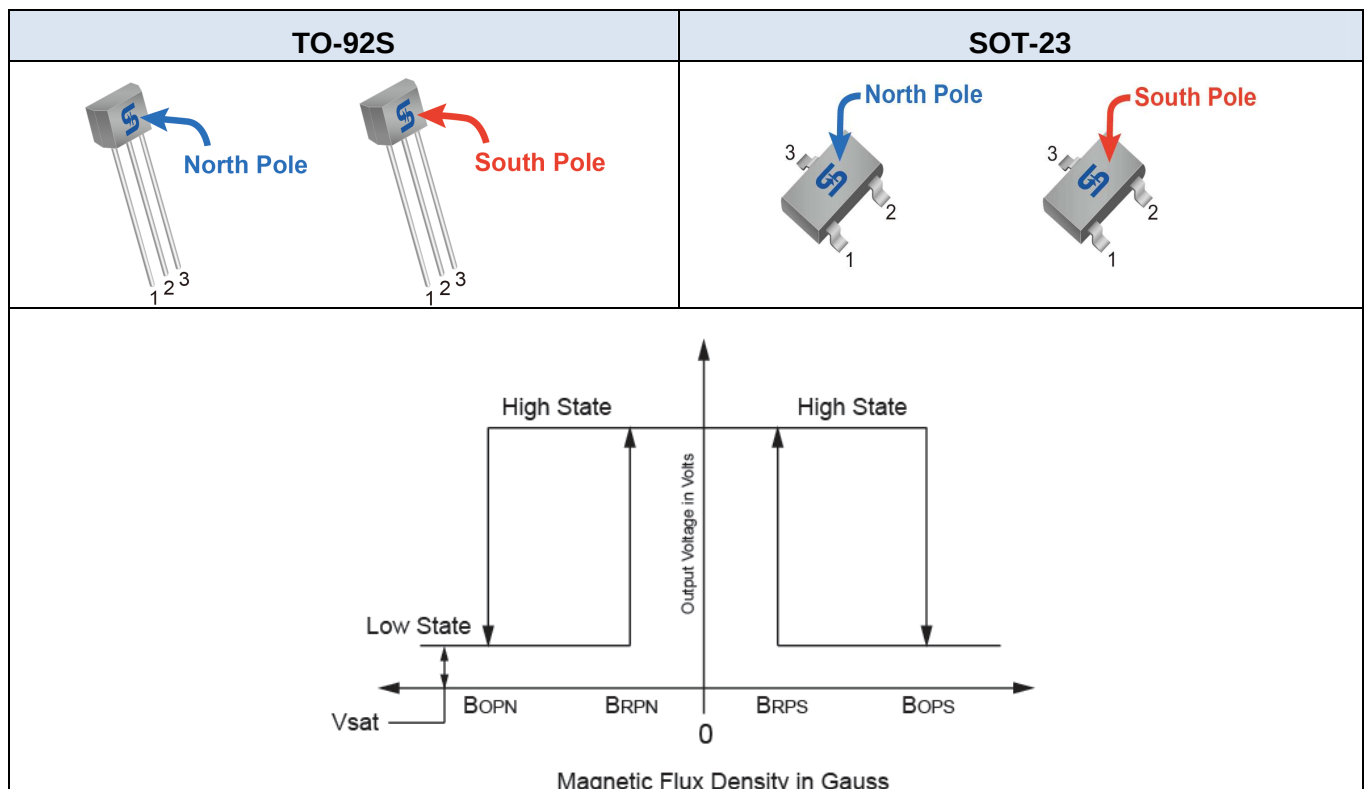
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Operating Point	B _{OPS}	N pole to branded side, B > B _{OP} , Vout On		30	55	Gauss
	B _{OPN}	S pole to branded side, B > B _{OP} , Vout On	-55	-30		Gauss
Release Point	B _{RPS}	N pole to branded side, B < B _{RP} , Vout Off	10	20		Gauss
	B _{RPN}	S pole to branded side, B < B _{RP} , Vout Off		-20	-10	Gauss
Hysteresis	B _{HYS}	B _{OPX} - B _{RPX}		10		Gauss

Note: 1G (Gauss) = 0.1mT (millitesta)

Output Behavior versus Magnetic Pole

DC Operating Parameters: T_A = -40 to 125°C, V_{CC} = 1.8V ~ 6V

Parameter	Test condition	OUT
South pole	B < Bop[(-55)~(-10)]	Low
Null or weak magnetic field	B = 0 or B < BRP	High
North pole	B > Bop(55~10)	Low



Characteristic Performance

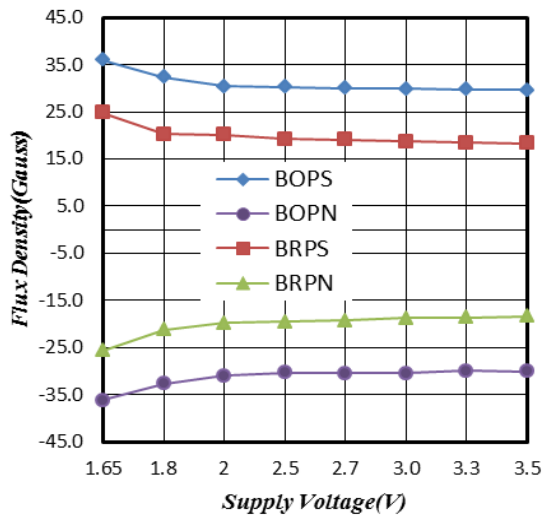


Figure 1. Supply Voltage vs. Flux Density

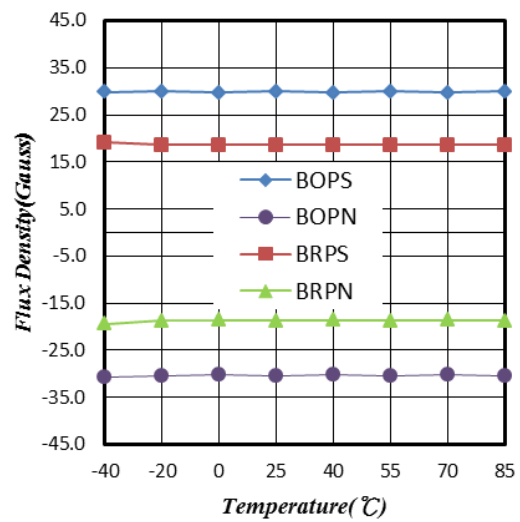


Figure 2. Temperature vs. Flux Density

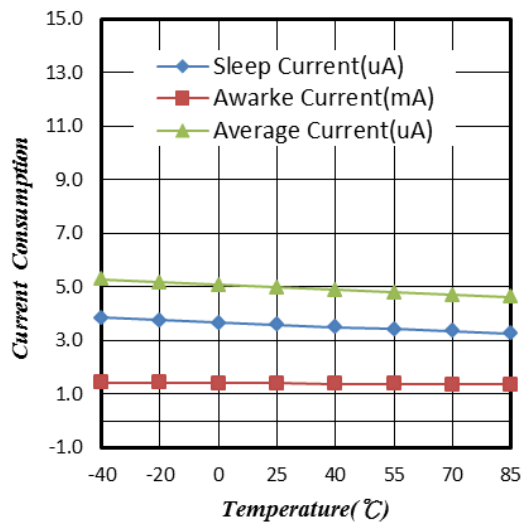


Figure 3. Supply Current vs. Temperature

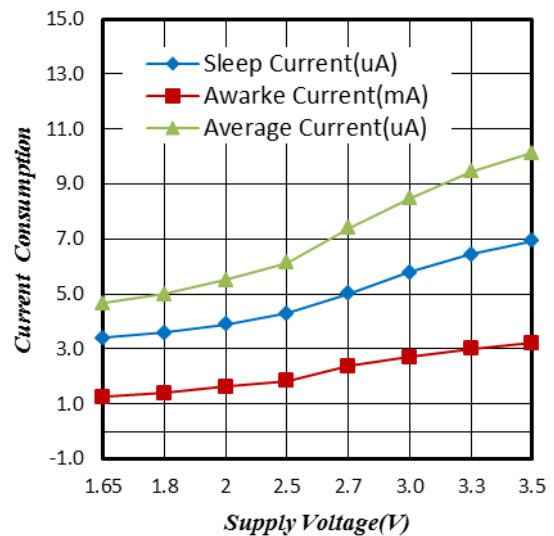


Figure 4. Supply Current vs. Supply Voltage

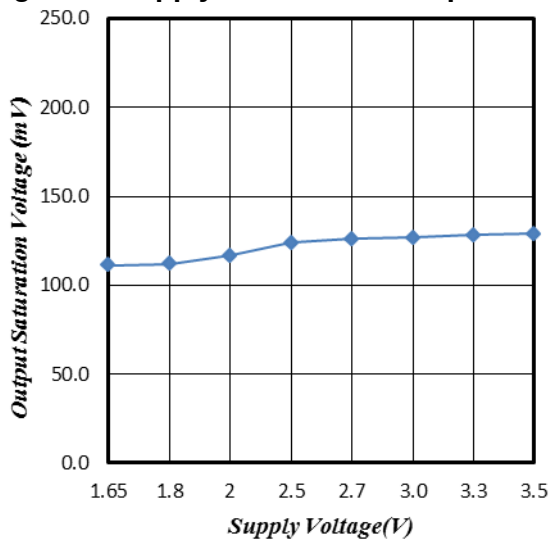


Figure 5. Output Saturation Voltage vs. Supply Voltage

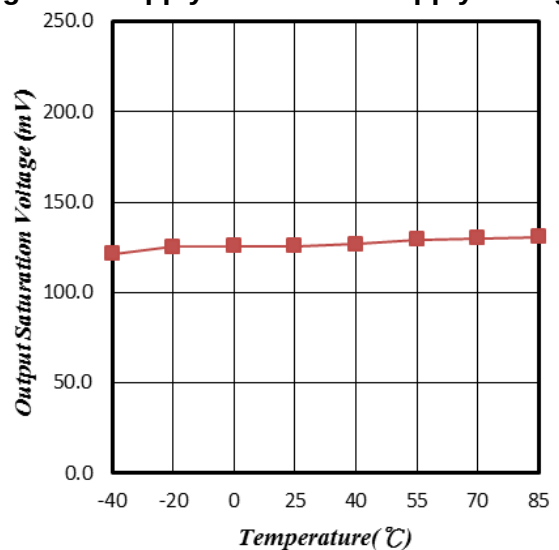


Figure 6. Output Saturation Voltage vs. Temperature

Characteristic Performance

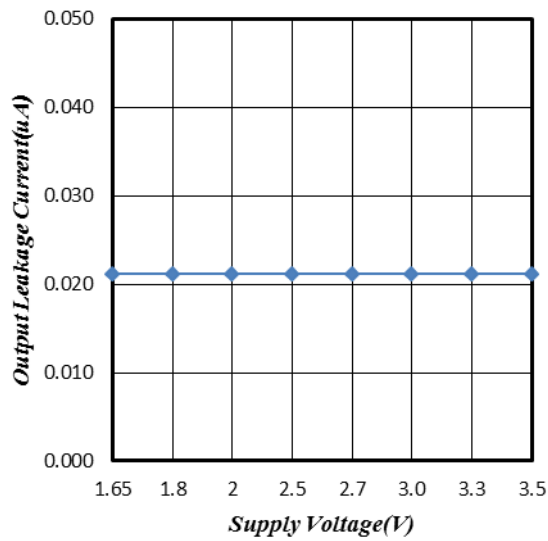


Figure 7. Output Leakage Current vs. Supply Voltage

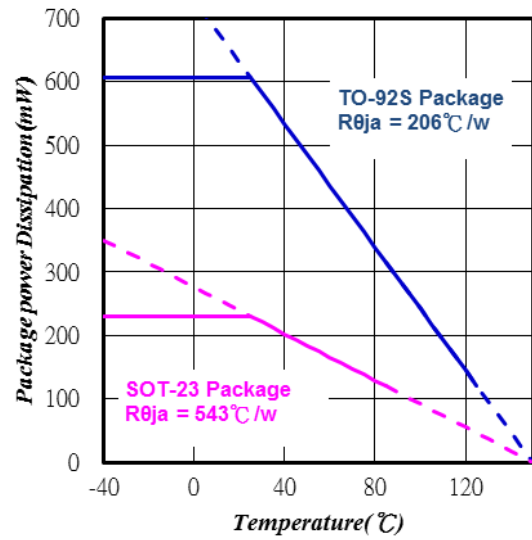
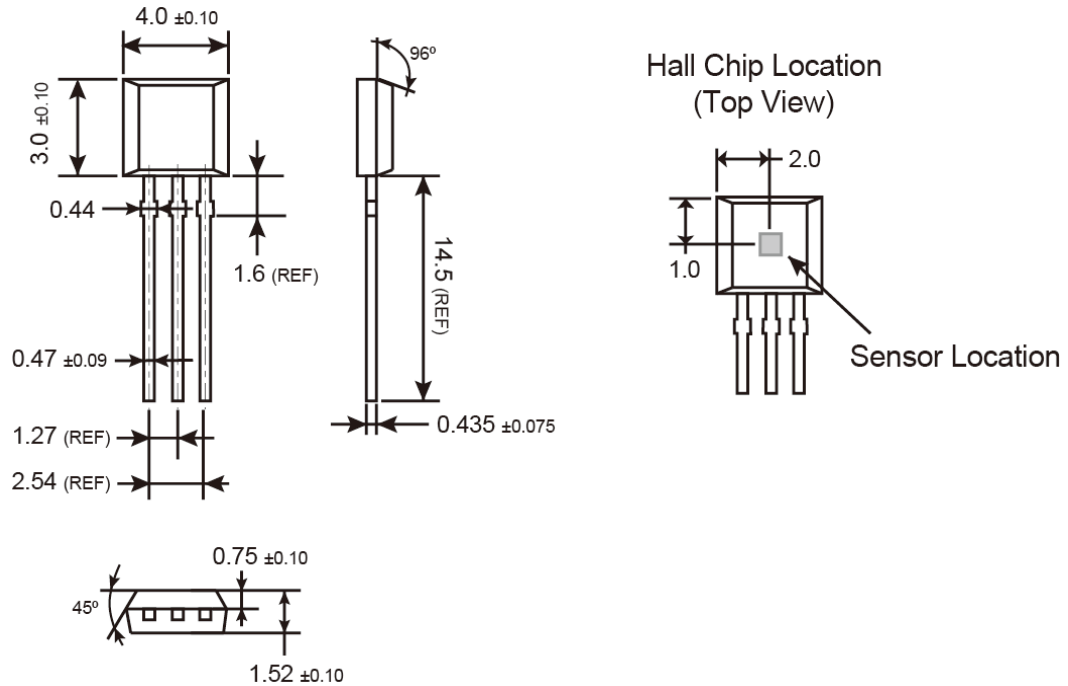


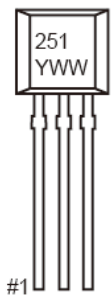
Figure 8. Power Dissipation vs. Temperature

TO-92S Mechanical Drawing



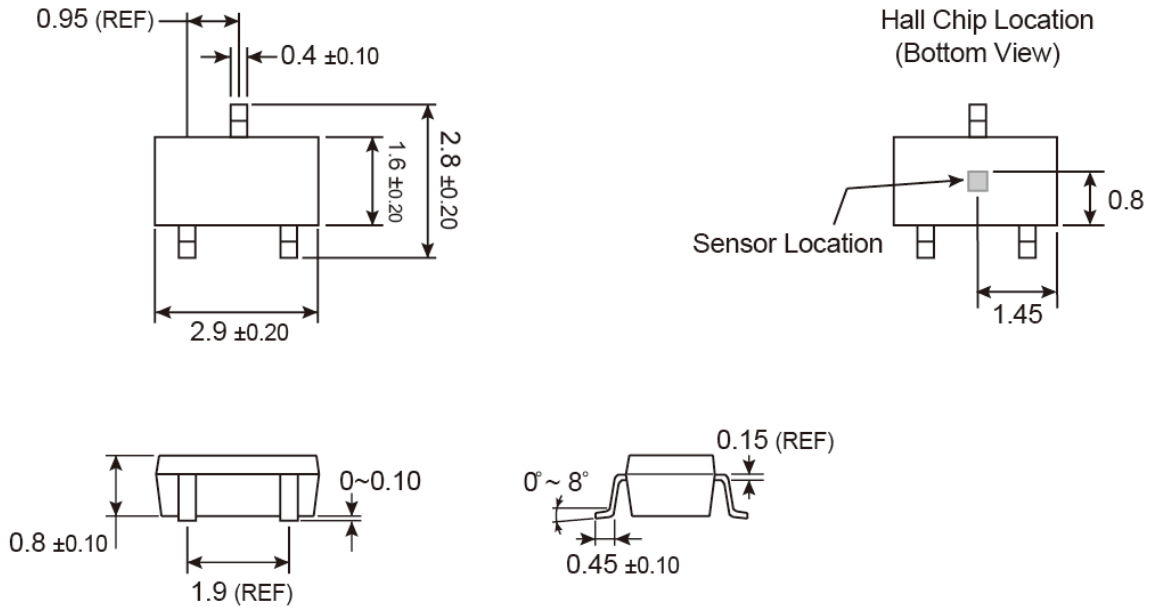
Unit: Millimeters

Marking Diagram



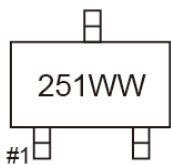
251 = Device Code
Y = Year Code (3=2013, 4=2014....)
WW = Week Code (01~52)

TSOT-23 Mechanical Drawing



Unit: Millimeters

Marking Diagram



251 = Device Code

WW = Week Code Table

week	1	2	3	4	5	6	7	8	9	10	11	12	13
code	OA	OB	OC	OD	OE	OF	OG	OH	OI	OJ	OK	OL	OM
week	14	15	16	17	18	19	20	21	22	23	24	25	26
code	ON	OO	OP	OQ	OR	OS	OT	OU	OV	OW	OX	OY	OZ
week	27	28	29	30	31	32	33	34	35	36	37	38	39
code	PA	PB	PC	PD	PE	PF	PG	PH	PI	PJ	PK	PL	PM
week	40	41	42	43	44	45	46	47	48	49	50	51	52
code	PN	PO	PP	PQ	PR	PS	PT	PU	PV	PW	PX	PY	PZ

TSH251

Micropower CMOS Output Hall Effect Switch

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